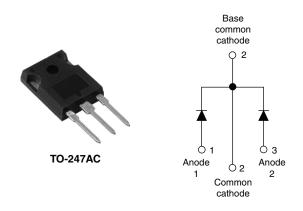
#### Vishay Semiconductors

### Hyperfast Rectifier, 2 x 40 A FRED Pt®



| PRODUCT SUMMARY                  |                |  |  |  |  |
|----------------------------------|----------------|--|--|--|--|
| Package                          | TO-247AC       |  |  |  |  |
| I <sub>F(AV)</sub>               | 2 x 40 A       |  |  |  |  |
| V <sub>R</sub>                   | 200 V          |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 1.02 V         |  |  |  |  |
| t <sub>rr</sub> (typ.)           | 34 ns          |  |  |  |  |
| T <sub>J</sub> max.              | 175 °C         |  |  |  |  |
| Diode variation                  | Common cathode |  |  |  |  |

#### FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Compliant to RoHS Directive 2002/95/EC

#### **DESCRIPTIONS/APPLICATIONS**

VS-80CPU02-F3 series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of welding, SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS                    |                                   |                         |             |       |  |
|---|-----------------------------------|-------------------------|-------------|-------|--|
| PARAMETER                                   | SYMBOL                            | TEST CONDITIONS         | MAX.        | UNITS |  |
| Repetitive peak reverse voltage             | V <sub>RRM</sub>                  |                         | 200         | V     |  |
| Average rectified forward currentper leg    |                                   | T <sub>C</sub> = 145 °C | 40          |       |  |
| total device                                | IF(AV)                            | 1 <sub>C</sub> = 143 0  | 80          | А     |  |
| Non-repetitive peak surge current per leg   | I <sub>FSM</sub>                  | T <sub>J</sub> = 25 °C  | 330         |       |  |
| Operating junction and storage temperatures | T <sub>J</sub> , T <sub>Stg</sub> |                         | - 65 to 175 | °C    |  |

| <b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                                     |   |      |      |      |       |  |
|--|-------------------------------------|---|------|------|------|-------|--|
| PARAMETER  | SYMBOL                              | TEST CONDITIONS                                 | MIN. | TYP. | MAX. | UNITS |  |
| Breakdown voltage,<br>blocking voltage   | V <sub>BR</sub> ,<br>V <sub>R</sub> | I <sub>R</sub> = 100 μA                         | 200  | -    | -    |       |  |
|  |                                     | I <sub>F</sub> = 40 A                           | -    | 0.94 | 1.02 |       |  |
|  | V                                   | I <sub>F</sub> = 40 A, T <sub>J</sub> = 150 °C  | -    | 0.80 | 0.90 | V     |  |
| Forward voltage  | V <sub>F</sub>                      | I <sub>F</sub> = 80 A                           | -    | 1.07 | 1.20 |       |  |
|  |                                     | I <sub>F</sub> = 80 A, T <sub>J</sub> = 150 °C  | -    | 0.97 | 1.08 |       |  |
|  |                                     | $V_{R} = V_{R}$ rated                           | -    | -    | 5    |       |  |
| Reverse leakage current  | IR                                  | $T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$ | -    | -    | 500  | μA    |  |
| Junction capacitance   | CT                                  | V <sub>R</sub> = 200 V                          | -    | 120  | -    | pF    |  |
| Series inductance  | L <sub>S</sub>                      | Measured lead to lead 5 mm from package body    | -    | 3.5  | -    | nH    |  |



COMPLIANT

### VS-80CPU02-F3

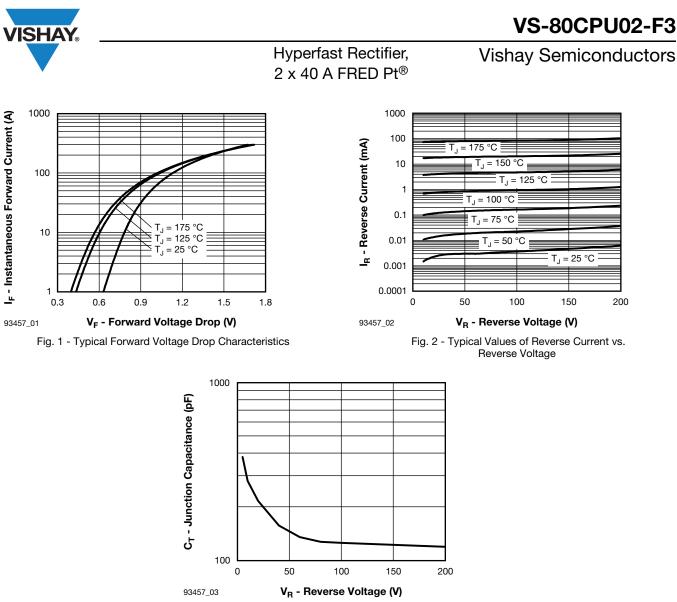
### Vishay Semiconductors

# Hyperfast Rectifier, 2 x 40 A FRED Pt®



| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified) |                        |   |   |      |      |       |         |  |
|---|------------------------|---|---|------|------|-------|---------|--|
| PARAMETER   | SYMBOL                 | TEST C  | MIN.  | TYP. | MAX. | UNITS |         |  |
|   |                        | $I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 1.0 \text{ A}$ | 100 A/µs, V <sub>R</sub> = 30 V   | -    | 34   | -     |         |  |
| Reverse recovery time   | t <sub>rr</sub>        | T <sub>J</sub> = 25 °C  |   | -    | 33   | -     | ns<br>A |  |
|   |                        | T <sub>J</sub> = 125 °C                                       | I <sub>F</sub> = 40 A<br>dI <sub>F</sub> /dt = - 200 A/μs<br>V <sub>B</sub> = 200 V | -    | 54   | -     |         |  |
| Deals receivers ourrent   | I <sub>RRM</sub>       | T <sub>J</sub> = 25 °C  |   | -    | 3.4  | -     |         |  |
| Peak recovery current   |                        | T <sub>J</sub> = 125 °C                                       |   | -    | 8    | -     |         |  |
|   | T <sub>J</sub> = 25 °C |   | -   | 56   | -    | nC    |         |  |
| Reverse recovery charge   | Q <sub>rr</sub>        | T <sub>J</sub> = 125 °C                                       |   | -    | 216  | -     | 10      |  |

| THERMAL - MECHANICAL SPECIFICATIONS                |                                   |  |              |      |            |                        |  |
|--|-----------------------------------|--|--------------|------|------------|------------------------|--|
| PARAMETER  | SYMBOL                            | TEST CONDITIONS                            | MIN.         | TYP. | MAX.       | UNITS                  |  |
| Maximum junction and storage temperature range     | T <sub>J</sub> , T <sub>Stg</sub> |  | - 65         | -    | 175        | °C                     |  |
| Thermal resistance,<br>junction to case per leg    | R <sub>thJC</sub>                 |  | -            | 0.46 | 0.70       |                        |  |
| Thermal resistance,<br>junction to ambient per leg | R <sub>thJA</sub>                 | Typical socket mount                       | -            | -    | 40         | °C/W                   |  |
| Thermal resistance, case to heatsink               | R <sub>thCS</sub>                 | Mounting surface, flat, smooth and greased | -            | 0.3  | -          |                        |  |
| Weight   |                                   |  | -            | 6.0  | -          | g                      |  |
| weight   |                                   |  | -            | 0.21 | -          | oz.                    |  |
| Mounting torque                                    |                                   |  | 6.0<br>(5.0) | -    | 12<br>(10) | kgf · cm<br>(lbf · in) |  |
| Marking device                                     |                                   | Case style TO-247AC                        |              | 80CI | PU02       |                        |  |





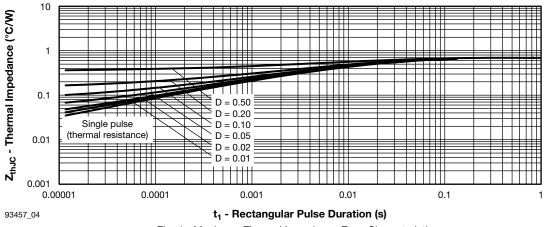
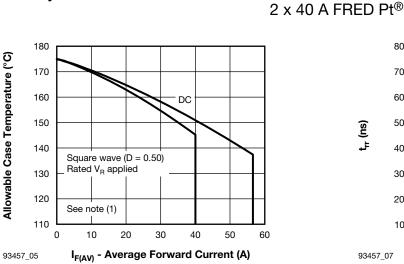
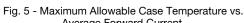


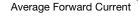
Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

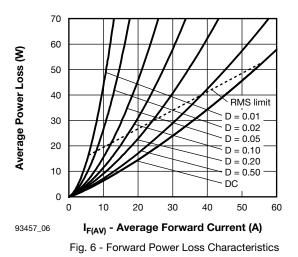
## **VS-80CPU02-F3**

**Vishay Semiconductors** 











#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ; Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = Rated  $V_R$

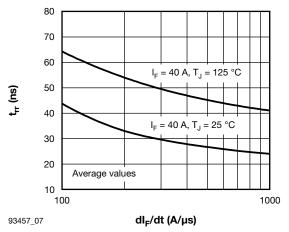


Fig. 7 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

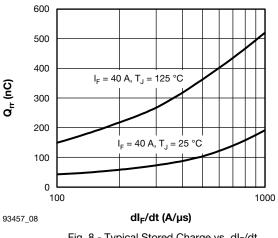


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

Hyperfast Rectifier,

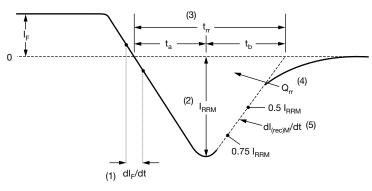


# Hyperfast Rectifier, 2 x 40 A FRED $Pt^{\mathbb{R}}$

**Vishay Semiconductors** 

### $V_{R} = 200 V$ $L = 70 \mu H$ D.U.T. $dI_{F}/dt$ adjust G IRFP250S

Fig. 9 - Reverse Recovery Parameter Test Circuit



(1) dl<sub>F</sub>/dt - rate of change of current through zero crossing

(4)  $\rm Q_{rr}$  - area under curve defined by  $\rm t_{rr}$  and  $\rm I_{\rm RRM}$ 

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(2)  ${\rm I}_{\rm RRM}$  - peak reverse recovery current

(3)  $t_{rr}$  - reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 9 - Reverse Recovery Waveform and Definitions

#### -80CPI 102-E3 VS

| VS-80CPU02-F3        |                                 |   |                               |  |                                       |    |     |  |
|----------------------|---------------------------------|---|-------------------------------|--|---------------------------------------|----|-----|--|
| Vishay Semiconducto  | ors                             |   | •••                           | ast Re<br>A FRE                        |                                       |    |     |  |
| ORDERING INFORMATION | TABLE                           |   |                               |  |                                       |    |     |  |
| Device code          | VS-                             | 80  | с                             | Р                                      | U                                     | 02 | -F3 |  |
|                      | 1<br>2<br>3<br>4<br>5<br>6<br>7 | - Cur<br>- Circ<br>- C =<br>- P =<br>- U =<br>- Vol | TO-247<br>Ultrafa<br>tage rat | st rectifie<br>ing (02 =<br>ntal digit | = 80 A)<br>n:<br>ode<br>er<br>= 200 V | )  | 7)  |  |

| ORDERING INFORMATION (Example) |  |      |                         |  |  |  |  |
|--------------------------------|--|------|-------------------------|--|--|--|--|
| PREFERRED P/N                  | QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION |      |                         |  |  |  |  |
| VS-80CPU02-F3                  | 25   | 1000 | Antistatic plastic tube |  |  |  |  |

| LINKS TO RELATED DOCUMENTS          |                          |  |  |  |  |
|-------------------------------------|--------------------------|--|--|--|--|
| Dimensions www.vishay.com/doc?95223 |                          |  |  |  |  |
| Part marking                        | www.vishay.com/doc?95007 |  |  |  |  |

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